



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

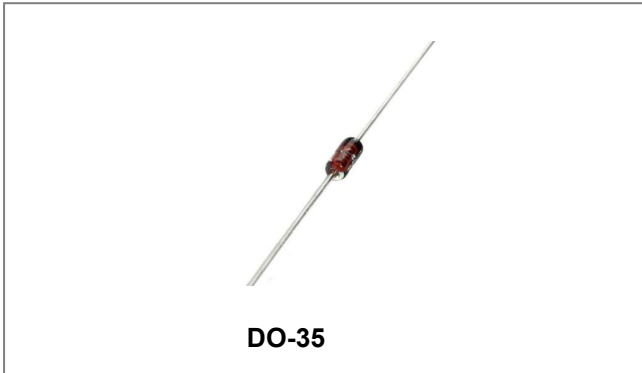
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



1N5225 THRU 1N5267 ZENER DIODES



Features

- Silicon Planar Power Zener Diodes
- Standard Zener voltage tolerance is $\pm 5\%$ with a "B" suffix.
- Other tolerances are available upon request.
- These diodes are also available in Mini-MELF case with the type designation ZMM5225 ... ZMM5267, SOT-23 case with the type designation MMBZ5265 ... MMBZ5267 and SOD-23 case with the types designation MMSZ5225 ... MMSZ5267.
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: DO-35 Glass Case
- Terminals: Plated axial leads, solderable per LIL-STD 750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: approx. 0.14 grams

Maximum Ratings@ $T_A=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Value	Units
Power Dissipation (Note 1)	P_D	500	mW
Forward Voltage @ $I_F = 200\text{mA}$	V_F	1.1	V
Typical Thermal resistance junction to Ambient Air (Note 1)	$R_{\theta JA}$	3000	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-65 to 200	$^\circ\text{C}$

Notes: 1. Valid provided that leads are kept at ambient temperature at a distance of 8mm from case

Ordering Information

Device	Package	Shipping
1N5225-1N5267	DO-35 (Pb-Free)	5000pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



1N5252 = Part Name

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Electrical Characteristics @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

Type	Nominal Zener Voltage ⁽³⁾ at I_{ZT} V_Z (V)	Test Current I_{ZT} (mA)	Maximum Zener impedance ⁽¹⁾		Typical Temperature Coefficient α_{VZ} (% / K)	Maximum Reverse Leakage Current		Maximum Regulator Current ⁽²⁾ I_{ZM} (mA)
			at I_{ZT} Z_{ZT} (Ω)	at $I_{ZK}=0.25\text{mA}$ Z_{ZK} (Ω)		I_R (μA)	Test Voltage V_R (V)	
1N5225	3.0	20	29	1600	-0.075	50	1.0	152
1N5226	3.3	20	28	1600	-0.070	25	1.0	138
1N5227	3.6	20	24	1700	-0.065	15	1.0	126
1N5228	3.9	20	23	1900	-0.060	10	1.0	115
1N5229	4.3	20	22	2000	-0.055	5.0	1.0	106
1N5230	4.7	20	19	1900	± 0.030	5.0	2.0	97
1N5231	5.1	20	17	1600	± 0.030	5.0	2.0	89
1N5232	5.6	20	11	1600	+0.038	5.0	3.0	81
1N5233	6.0	20	7	1600	+0.038	5.0	3.5	76
1N5234	6.2	20	7	1000	+0.045	5.0	4.0	73
1N5235	6.8	20	5	750	+0.050	3.0	5.0	67
1N5236	7.5	20	6	500	+0.058	3.0	6.0	61
1N5237	8.2	20	8	500	+0.062	3.0	6.5	55
1N5238	8.7	20	8	600	+0.065	3.0	6.5	52
1N5239	9.1	20	10	600	+0.068	3.0	7.0	50
1N5240	10	20	17	600	+0.075	3.0	8.0	45
1N5241	11	20	22	600	+0.076	2.0	8.4	41
1N5242	12	20	30	600	+0.077	1.0	9.1	38
1N5243	13	9.5	13	600	+0.079	0.5	9.9	35
1N5244	14	9.0	15	600	+0.082	0.1	10	32
1N5245	15	8.5	16	600	+0.082	0.1	11	30
1N5246	16	7.8	17	600	+0.083	0.1	12	28
1N5247	17	7.4	19	600	+0.084	0.1	13	27
1N5248	18	7.0	21	600	+0.085	0.1	14	25
1N5249	19	6.6	23	600	+0.086	0.1	14	24
1N5250	20	6.2	25	600	+0.086	0.1	15	23
1N5251	22	5.6	29	600	+0.087	0.1	17	21
1N5252	24	5.2	33	600	+0.087	0.1	18	19.1
1N5253	25	5.0	35	600	+0.089	0.1	19	18.2
1N5254	27	4.6	41	600	+0.090	0.1	21	16.8
1N5255	28	4.5	44	600	+0.091	0.1	21	16.2
1N5256	30	4.2	49	600	+0.091	0.1	23	15.1
1N5257	33	3.8	58	700	+0.092	0.1	25	13.8
1N5258	36	3.4	70	700	+0.093	0.1	27	12.6
1N5259	39	3.2	80	800	+0.094	0.1	30	11.6
1N5260	43	3.0	93	900	+0.095	0.1	33	10.6
1N5261	47	2.7	105	1000	+0.095	0.1	36	9.7
1N5262	51	2.5	125	1100	+0.096	0.1	39	8.9
1N5263	56	2.2	150	1300	+0.096	0.1	43	-
1N5264	60	2.1	170	1400	+0.097	0.1	46	-
1N5265	62	2.0	185	1400	+0.097	0.1	47	-
1N5266	68	1.8	230	1600	+0.097	0.1	52	-
1N5267	75	1.7	270	1700	+0.098	0.1	56	-

Note: (1) The Zener impedance is derived from the 1 kHz AC voltage which results when an AC current having an RMS value equal to 10% of the Zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units

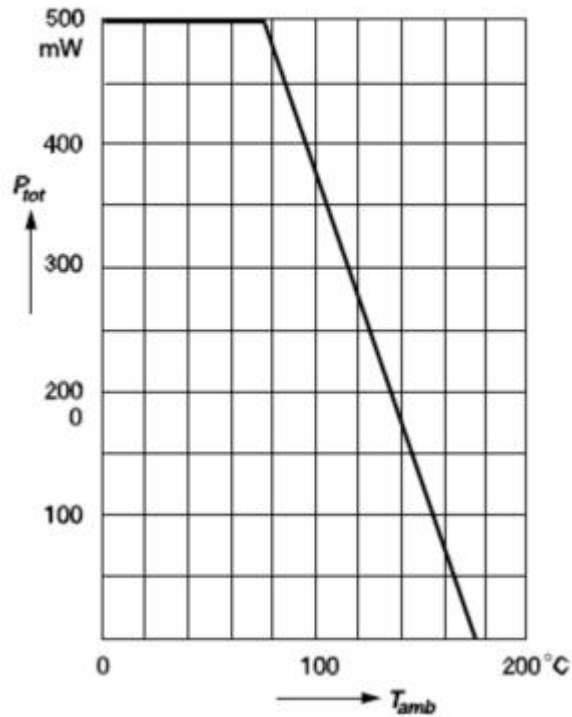
(2) Valid provided that leads at a distance of 10 mm from case are kept at ambient temperature

(3) Measured with device junction in thermal equilibrium

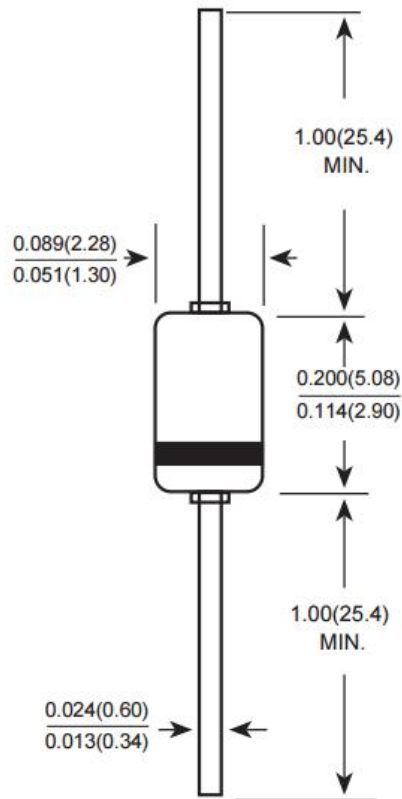
Ratings and Characteristics Curves

**Admissible power dissipation
versus ambient temperature**

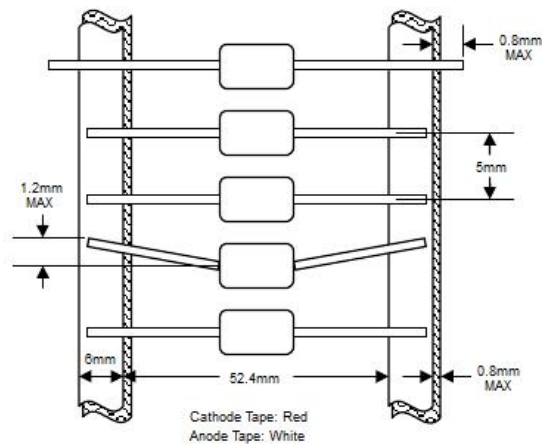
Valid provided that leads at a distance of 10 mm
from case are kept at ambient temperature



Mechanical Dimensions DO-35(Inches/Millimeters)



Carrier Tape Specification DO-35



DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..